

Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance.

2. Features and benefits

- High blocking voltage capability
- High noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| Symbol | Parameter | Conditions Values | | lues | | Unit | |
|--------------------------------|--|--|-------------|------|------|------|----|
| Absolute | maximum rating | | | | | | |
| V_{DRM} | repetitive peak off-state voltage | | | 6 | 600 | | V |
| $I_{\mathrm{T}(\mathrm{RMS})}$ | RMS on-state current | full sine wave; T _{mb} ≤ 91 °C; <u>Fig. 1; Fig. 2; Fig. 3</u> | 25 | | A | | |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | 190 | | A | | |
| Symbol | Parameter | Conditions | Min Typ Max | | Unit | | |
| Static ch | aracteristics | | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 6 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 10 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 11 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u> | | - | 23 | 70 | mA |

5. Pinning information

| Table 2. P | inning infor | mation | | |
|------------|--------------|--------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | |
| 2 | T2 | main terminal 2 | | |
| 3 | G | gate | | sym051 |
| mb | T2 | mounting base; main terminal 2 | | symosi |
| | | | | |

6. Ordering information

| Table 3. Ordering inform | nation | | | |
|--------------------------|----------|---|---------|--|
| Type number | Package | kage | | |
| | Name | Description | Version | |
| BTA140-600 | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | |

7. Marking

| Table 4. Marking codes | |
|------------------------|---------------|
| Type number | Marking codes |
| BT140-600 | BT140-600 |

8. Limiting values

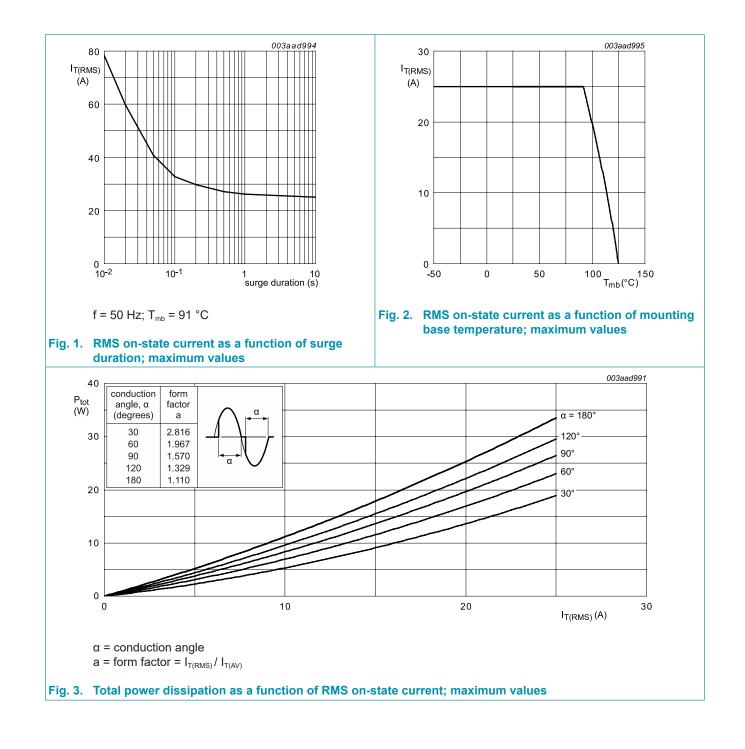
Table 5. Limiting values

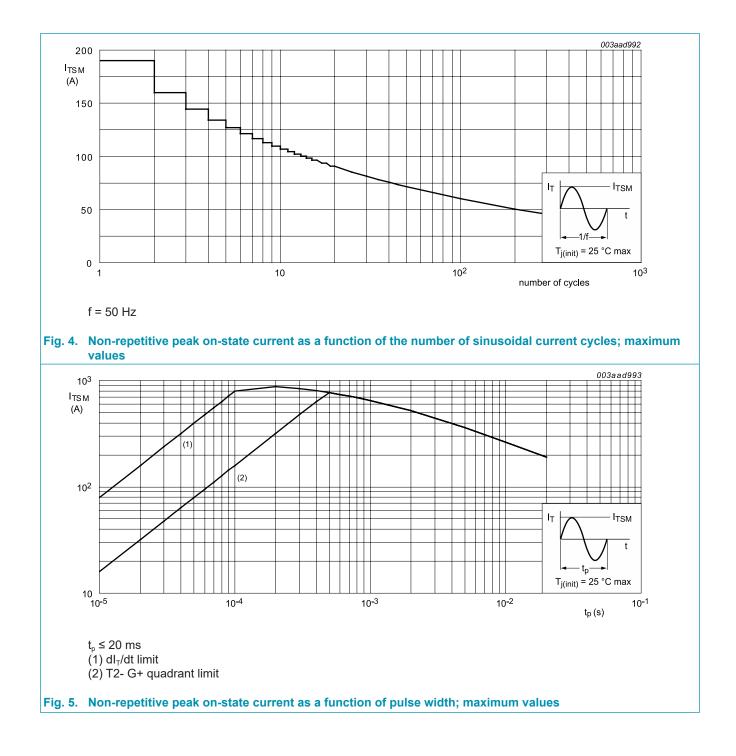
In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Values | Unit |
|---------------------|--|---|------------|------------------|
| V_{DRM} | repetitive peak off-state voltage | | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤91°C; <u>Fig 1</u> ; <u>Fig 2</u> ; <u>Fig 3</u> | 25 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \frac{\text{Fig 4}}{2}; \frac{\text{Fig 5}}{2}$ | 190 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | 209 | A |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | 180 | A ² s |
| dl _⊤ /dt | rate of rise of on-state current | I _G = 70 mA; T2+ G+ | 50 | A/µs |
| | | I _G = 70 mA; T2+ G- | 50 | A/µs |
| | | I _G = 70 mA; T2- G- | 50 | A/µs |
| | | I _G = 140 mA; T2- G+ | 10 | A/µs |
| I _{GM} | peak gate current | | 2 | Α |
| P _{GM} | peak gate power | | 5 | W |
| $P_{G(AV)}$ | average gate power | over any 20 ms period | 0.5 | W |
| T _{stg} | storage temperature | | -40 to 150 | °C |
| Tj | junction temperature | | 125 | °C |

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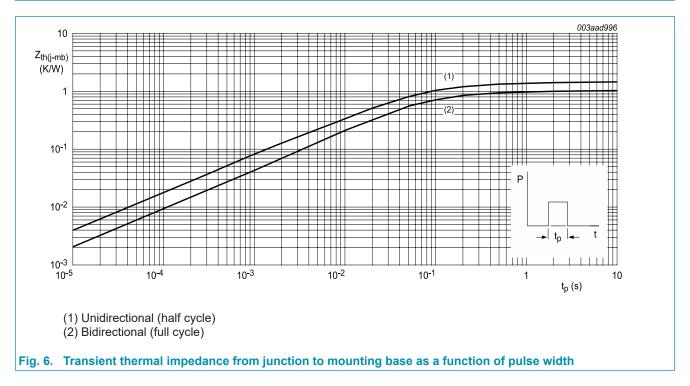
BTA140-600 4Q Triac





9. Thermal characteristics

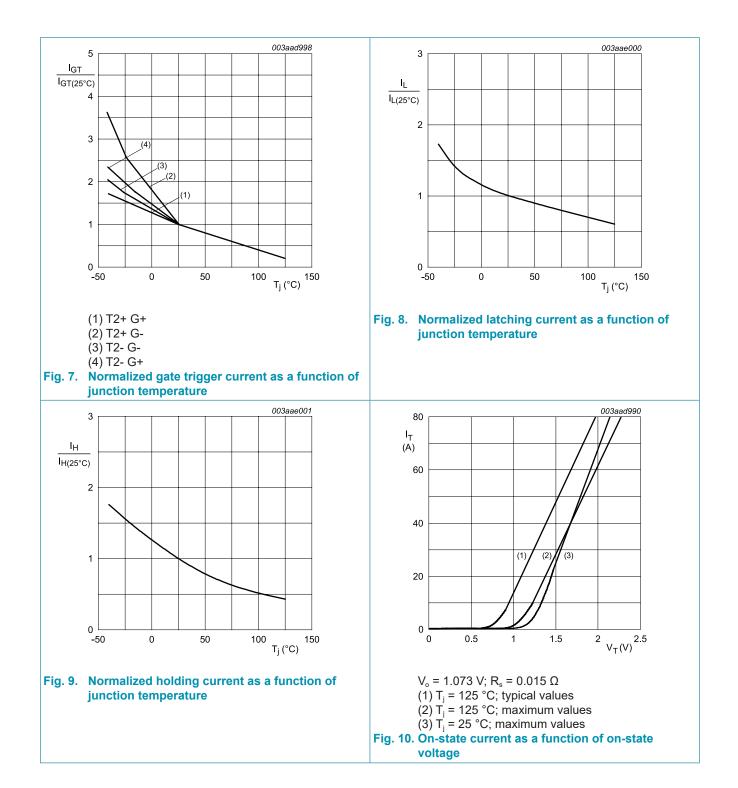
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|--------------------------|-----|-----|-----|------|
| $R_{\text{th(j-mb)}}$ | thermal resistance from junction to mounting base | full cycle; <u>Fig 6</u> | - | - | 1 | K/W |
| | | half cycle; <u>Fig 6</u> | - | - | 1.4 | K/W |
| $R_{\text{th(j-a)}}$ | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



10. Characteristics

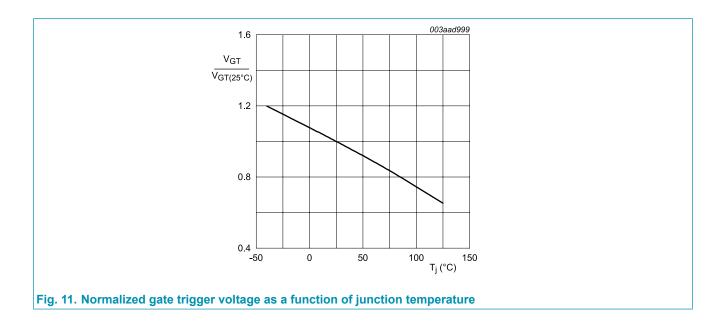
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---|------|-----|------|------|
| Static ch | aracteristics | 11 | | | | |
| I _{GT} | gate trigger current | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 \text{ °C}; \text{ Fig. 7}$ | - | 6 | 35 | mA |
| | | V_{D} = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 10 | 35 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7 | - | 11 | 35 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$ | - | 23 | 70 | mA |
| I _L | latching current | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$ | - | 8 | 40 | mA |
| | | V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | 30 | 60 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 18 | 40 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 15 | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; T2+; <u>Fig. 9</u> | - | 7 | 60 | mA |
| | | V _D = 12 V; T _j = 25 °C; T2-; Fig. 9 | | 12 | 60 | mA |
| V _T | on-state voltage | I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.3 | 1.55 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; <u>Fig. 11</u> | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic | characteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit | 100 | 300 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_D = 400 \text{ V}; \text{ T}_j = 95 \text{ °C}; \text{ dI}_{com}/\text{dt} = 9 \text{ A}/\text{ms}; \text{ I}_T = 25 \text{ A}; \text{ gate open circuit}$ | - | 10 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | $I_{TM} = 30 \text{ A}; V_D = 600 \text{ V}; I_G = 0.1 \text{ A}; \text{ d}I_G/\text{ d}t = 5 \text{ A}/\mu\text{s}$ | - | 2 | - | μs |

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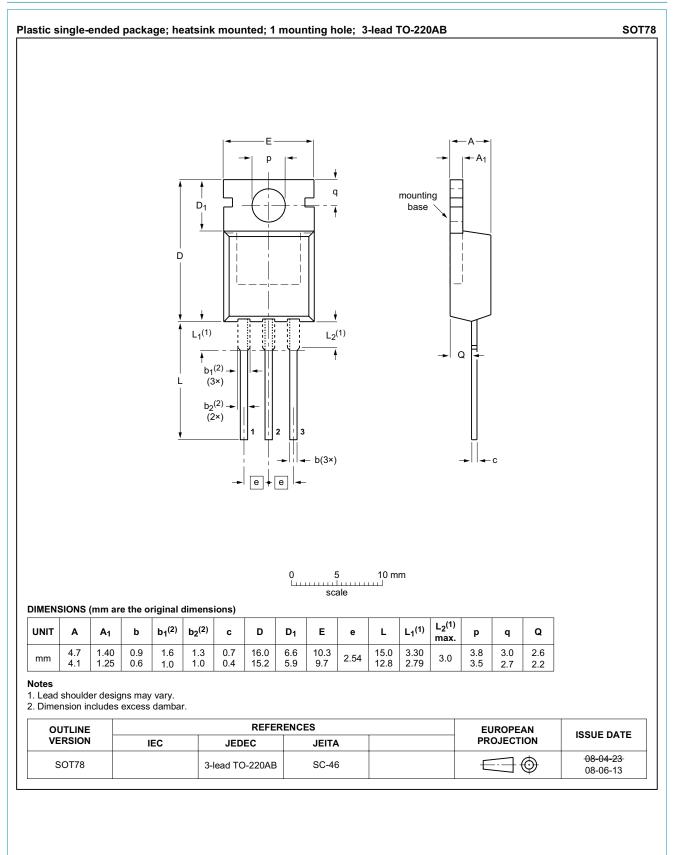


4Q Triac

BTA140-600



11. Package outline



Product data sheet

BTA140-600

12. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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